

Nips Thyristor Modules/Water Cooling MD1000T**W MR1000T**W MC1000T**W

Features:

- Isolated mounting base 2500V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications :

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

| V_{DSM}, V_{RSM} | V_{DRM}, V_{RRM} | 品名 |
|--------------------|--------------------|-------------|
| 900V | 800V | Mx1000T80W |
| 1100V | 1000V | Mx1000T100W |
| 1300V | 1200V | Mx1000T120W |
| 1500V | 1400V | Mx1000T140W |
| 1700V | 1600V | Mx1000T160W |
| 1900V | 1800V | Mx1000T180W |

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | T_j (°C) | VALUE | | | UNIT |
|------------------------|--|--|------------|-------|------|-------|--------------------|
| | | | | Min. | Typ. | Max. | |
| $I_{T(AV)}$ | Mean on-state current | 180° half sine wave 50Hz Single side cooled, $T_c=55^\circ C$ | 125 | | | 1000 | A |
| $I_{T(RMS)}$ | RMS on-state current | | | | | 1570 | A |
| V_{DRM}/V_{RRM} | Repetitive peak off-state voltage Repetitive peak reverse voltage | tp=10ms | 125 | 800 | | 1800 | V |
| I_{DRM} I_{RRM} | Repetitive peak current | at V_{DRM} at V_{RRM} | 125 | | | 55 | mA |
| I_{TSM} | Surge on-state current | 10ms half sine wave, $V_R=0.6V_{RRM}$ | 125 | | | 26.0 | kA |
| I^2t | I^2t for fusing coordination | | | | | 3380 | $A^2s \times 10^3$ |
| V_{TO} | Threshold voltage | | 125 | | | 0.81 | V |
| r_T | On-state slope resistance | | | | | 0.21 | $m\Omega$ |
| V_{TM} | Peak on-state voltage | | | 25 | | 2.0 | V |
| dv/dt | Critical rate of rise of off-state voltage | $V_{DM}=67\%V_{DRM}$ | 125 | | | 800 | $V/\mu s$ |
| di/dt | Critical rate of rise of on-state current | Gate source 1.5A $t \leq 0.5\mu s$ Repetitive | 125 | | | 100 | $A/\mu s$ |
| I_{GT} | Gate trigger current | $V_A=12V, I_A=1A$ | 25 | 30 | | 200 | mA |
| V_{GT} | Gate trigger voltage | | | 1.0 | | 3.0 | V |
| I_H | Holding current | | | 20 | | 200 | mA |
| V_{GD} | Non-trigger gate voltage | $V_{DM}=67\%V_{DRM}$ | 125 | 0.2 | | | V |
| I_{GD} | Non-trigger gate current | $V_{DM}=67\%V_{DRM}$ | 125 | 1.5 | | | mA |
| $R_{th(j-c)}$ | Thermal resistance Junction to case | D.C. Single side cooled, per chip. DC | | | | 0.052 | $^\circ C/W$ |
| $R_{th(c-w)}$ | Thermal resistance case to water | D.C. Single side cooled, per chip. (6L/min) | | | | 0.037 | $^\circ C/W$ |
| V_{iso} | Isolation voltage | 50Hz,R.M.S,t=1min, $I_{iso}:1mA(MAX)$ | | 2500 | | | V |
| F_m | Terminal connection torque(M12) | | | 12.0 | | 16.0 | $N \cdot m$ |
| | Mounting torque(M8) | | | 10.0 | | 12.0 | $N \cdot m$ |
| T_{vj} | Junction temperature | | | -40 | | 125 | $^\circ C$ |
| T_{stg} | Stored temperature | | | -40 | | 125 | $^\circ C$ |
| T_{water} | Water temperature | Water flow=6L/min | | - | | 30 | $^\circ C$ |
| - | Water Pressure loss | | | | 41 | | kPa |
| W_t | Weight | | | | 3220 | | g |
| Outline | | M15 | | | | | |

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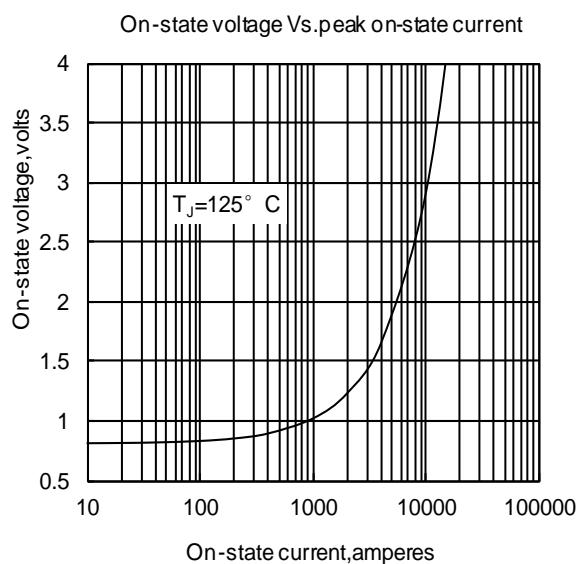


Fig1

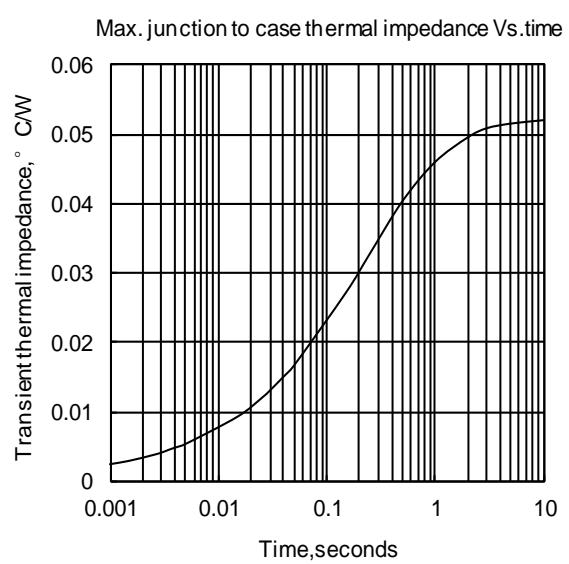


Fig2

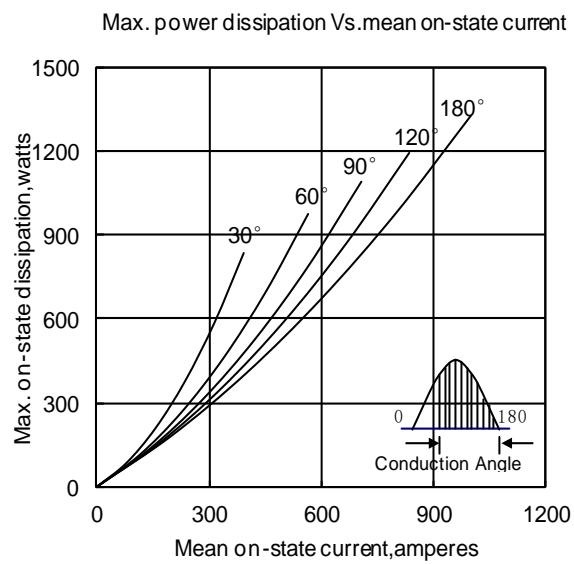


Fig3

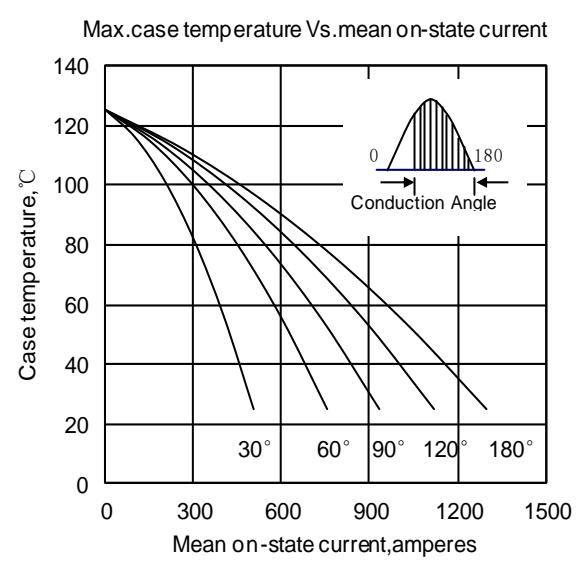


Fig4

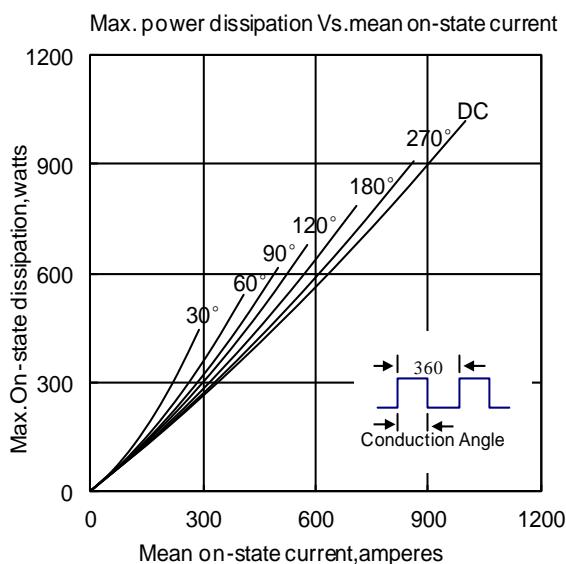


Fig5

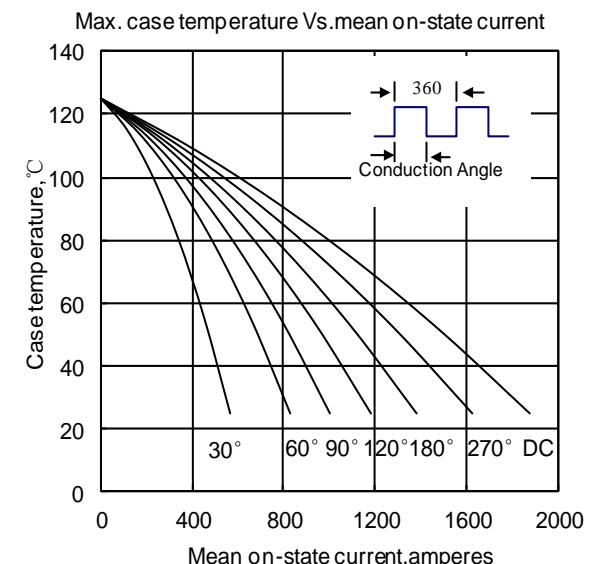


Fig6

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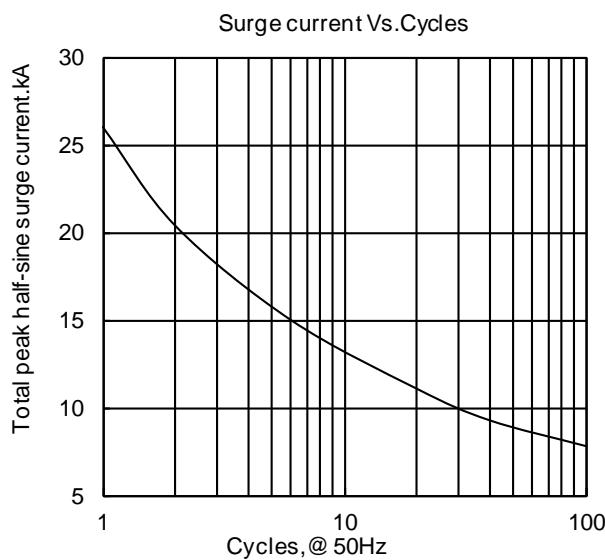


Fig7

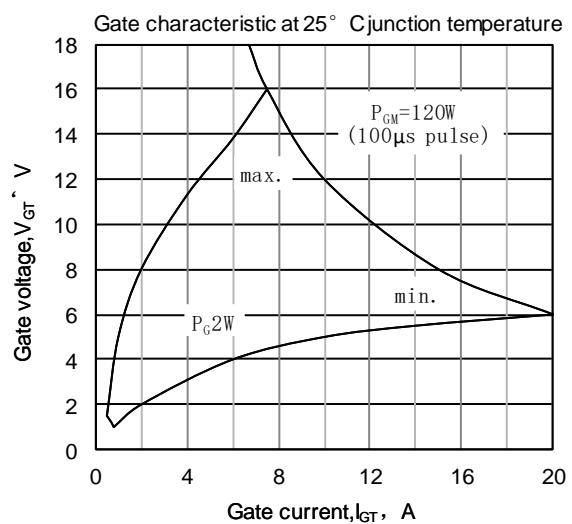


Fig8

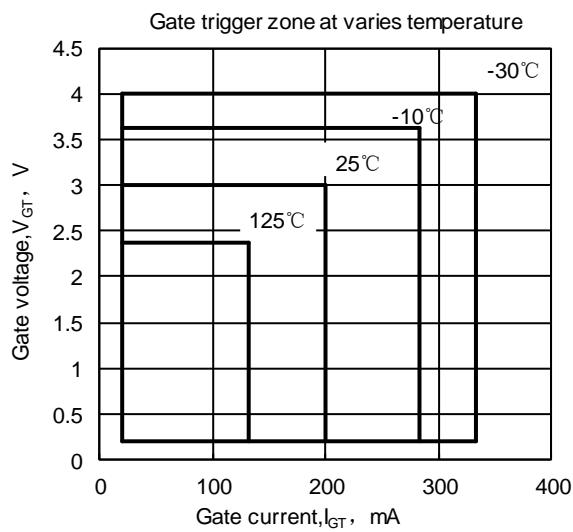


Fig9

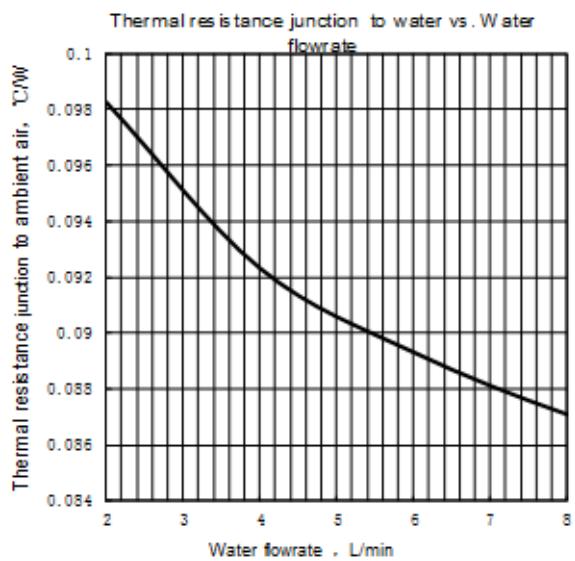


Fig. 10

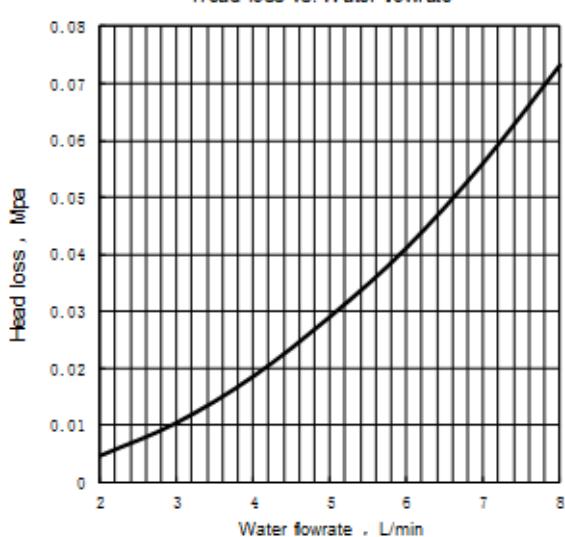
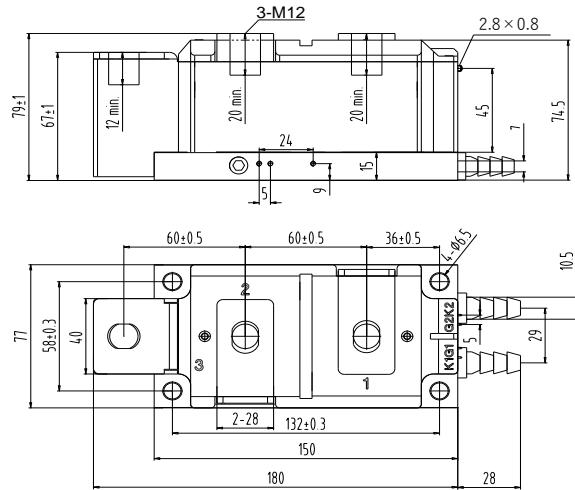


Fig. 11

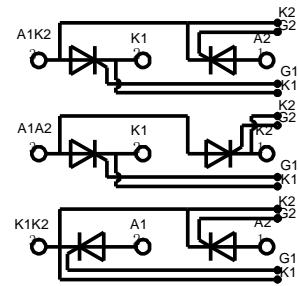
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MD1000T**W

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Unmarked dimensional tolerance : $\pm 0.5\text{mm}$